TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WZ245FU,TC7WZ245FK

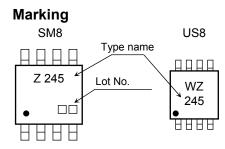
#### **Dual Bus Transceiver**

#### Features

- High output drive :  $\pm 24$  mA (min) at V<sub>CC</sub> = 3 V
- Super high speed operation : t<sub>pd</sub> = 5.0 ns(max)

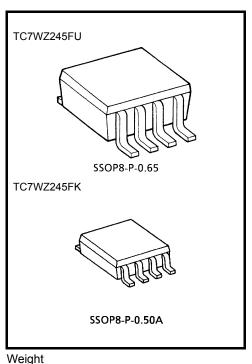
at V<sub>CC</sub> = 5 V, 50 pF

- Operation voltage range : V<sub>CC (opr)</sub> = 1.65~5.5 V
- 5.5-V tolerant inputs
- 5.5-V power down protection outputs
- Matches the performance of TC74LCX series when operated at 3.3-V  $V_{CC}$
- Note : Do not apply a signal to any pins when it is the output mode. Damage may result. All floating (high impedance) bus pins must have their input levels fixed by means of pull-up or pull-down resistors.



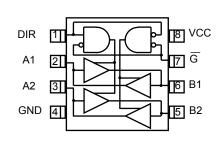
# Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V <sub>CC</sub>	-0.5~6	V	
DC input voltage	V <sub>IN</sub>	-0.5~6	V	
DC output voltage	V <sub>OUT</sub>	-0.5~6	V	
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	lok	-20	mA	
DC output current	IOUT	±50	mA	
DC V <sub>CC</sub> /ground current	ICC	±50	mA	
Power dissipation	PD	300 (SM8) 200 (US8)	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	
Lead temperature (10 s)	ΤL	260	°C	



SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

# Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# **Truth Table**

INPUT		FUNC	OUTPUT		
G	DIR	IR A BUS B BUS		OULLO	
L	L	OUTPUT	INPUT	A = B	
L	Н	INPUT	OTPUT	B = A	
Н	Х	HIgh Im	Z		

X : Don't Care

Z : High Impedance

# **Operating Ranges**

Characteristics	Symbol	Rating	Unit	
Supply voltage	N/	1.65~5.5	V	
	V <sub>CC</sub>	1.5~5.5 (Note 1)	v	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V	
		0~ V <sub>CC</sub> (Note 3)	v	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dv	0~20 ( $V_{CC}$ = 1.8 V $\pm$ 0.15 V , 2.5 V $\pm$ 0.2 V )		
		0~10 ( $V_{CC}$ = 3.3 V $\pm$ 0.3 V )	ns/V	
		0~5 ( $V_{CC}$ = 5.5 V $\pm$ 0.5 V )		

Note 1 : Data retention only

Note 2 : V<sub>CC cc=</sub> 0 V

Note 3 : High or low state

# **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		I Test Condition			-	Ta = 25°C Ta = -40~85			0~85°C	- Unit
				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
High-Level VIH				1.65~1.95	V <sub>CC</sub> × 0.75		_	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$	_	
Input Voltage	VIH	_		2.3~5.5	$V_{CC} \times 0.7$		_	$V_{CC} \times 0.7$		V
Low-Level	Ma	VIL —		1.65~1.95	_		V <sub>CC</sub> × 0.25		V <sub>CC</sub> × 0.25	
Input Voltage	VIL			2.3~5.5	_		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	
				1.65	1.55	1.65	_	1.55		
			I <sub>OH</sub> = -100 μA	2.3	2.2	2.3		2.2		
			10H100 μA	3.0	2.9	3.0		2.9		
High-level output voltage				4.5	4.4	4.5		4.4		
	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -4 mA	1.65	1.29	1.52		1.29		
		0	I <sub>OH</sub> = -8 mA	2.3	1.9	2.14		1.9		
			I <sub>OH</sub> = -16 mA	3.0	2.4	2.75		2.4		
			I <sub>OH</sub> = -24 mA	3.0	2.3	2.62	_	2.3	_	
			I <sub>OH</sub> = -32 mA	4.5	3.8	4.13	—	3.8	_	
			I <sub>OH</sub> = 100 μA	1.65	—	0	0.1	_	0.1	
				2.3	_	0	0.1	_	0.1	
				3.0	_	0	0.1	_	0.1	
				4.5	_	0	0.1	_	0.1	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = 4 mA	1.65	_	0.08	0.24	_	0.24	
		0	I <sub>OH</sub> = 8 mA	2.3		0.1	0.3		0.3	
			I <sub>OH</sub> = 16 mA	3.0		0.16	0.4		0.4	
			I <sub>OH</sub> = 24 mA	3.0		0.24	0.55		0.55	
			I <sub>OH</sub> = 32 mA	4.5		0.25	0.55		0.55	1
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0~5.5			±1		±10	μA
3-State Output Off-State Current	I <sub>OZ</sub>	VIN=VIH or VIL VOUT=VCC or GND		1.65~ 5.5	_		±0.5		±5	μA
Power off leakage current	IOFF	$V_{IN}$ or $V_{OUT} = 5.5 V$		0.0		_	1	_	10	μA
Quiescent supply current	ICC	$V_{IN} = 5.5 V \text{ or GND}$		1.65~5.5		_	1		10	μA

## AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol Test Condition			Ta = 25°C			Ta = −40~85°C		Unit
Gilaraciensilos Symbol		Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
		$C_L = 15 \text{ pF}, \text{ R}_L = 1 \text{ M}\Omega$	$1.8\pm0.15$	2.0		15.0	2.0	16.5	ns
			$\textbf{2.5}\pm\textbf{0.2}$	1.0	_	7.5	1.0	8.0	
Propagation delay time	t <sub>pLH</sub>	$O_{L} = 10 \text{ pr},        $	$\textbf{3.3}\pm\textbf{0.3}$	0.8	_	5.2	1.2	6.0	
Tropagation delay time	t <sub>pHL</sub>		$5.0\pm0.5$	0.5		4.5	0.8	5.5	115
		$C_{L} = 50 \text{ pF}, R_{L} = 500 \Omega$	$\textbf{3.3}\pm\textbf{0.3}$	1.5		6.7	1.5	7.0	
		CL = 50 pr , RL = 500 32	$5.0\pm0.5$	0.8		5.0	0.8	5.3	
			$1.8\pm0.15$	2.0		20.0	2.0	22.0	ns
3 state output Enable time	<sup>t</sup> pZL pZH	$C_L = 50 \text{ pF}, \text{ R}_L = 500 \Omega$	$2.5\pm0.2$	1.8		10.5	1.8	11.2	
3-state output Enable time			$\textbf{3.3}\pm\textbf{0.3}$	1.5	_	8.1	1.5	8.5	
			$5.0\pm0.5$	0.8	_	5.5	0.8	5.8	
	t <sub>pLZ</sub> t <sub>pHZ</sub>	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$1.8\pm0.15$	2.5		17.0	2.5	18.8	ns
3-state output Disable time			$2.5\pm0.2$	1.5		8.6	1.5	9.1	
5-state output Disable time			$\textbf{3.3}\pm\textbf{0.3}$	1.5		7.1	1.5	7.5	
			$5.0\pm0.5$	0.3		4.7	0.3	5.0	
Output to output skew	tos <sub>LH</sub>	(Note 4)	$\textbf{3.3}\pm\textbf{0.3}$			1.0		1.0	ns
	tos <sub>HL</sub>	(11018 4)	$5.0 \pm 0.5$			0.8	_	0.8	
Input capacitance	C <sub>IN</sub>	DIR,DE	0	_	7	_	_	_	pF
Bus input capacitance	C <sub>I / 0</sub>	An,Bn	5.5		8	_	_		pF
Power dissipation	Con	(Note 5)	3.3	_	29			—	рĒ
capacitance	C <sub>PD</sub>		5.5		33				pF

Note 4 :Parameter guaranteed by desigh.  $t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$ 

Note 5 :  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

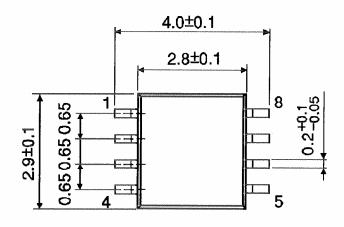
Average operating current can be obtained by the equation:  $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ 

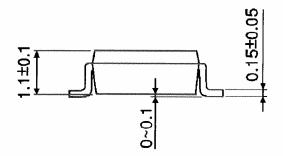
# **TOSHIBA**

# **Package Dimensions**

#### SSOP8-P-0.65

Unit : mm



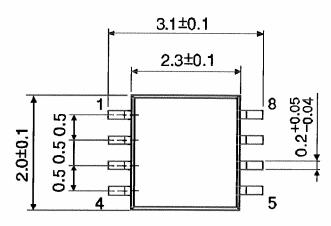


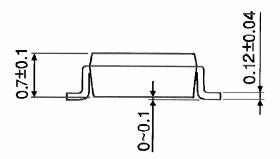
Weight: 0.02 g (typ.)

# Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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20070701-EN GENERAL

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